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NPN SILICON RF TRANSISTOR NE68518 / 2SC5015 Jeita Part No.

NPN EPITAXIAL SILICON RF TRANSISTOR FOR HIGH-FREQUENCY LOW-NOISE AMPLIFICATION 4-PIN SUPER MINIMOLD (18)

FEATURES

- High fr: fr = 12 GHz TYP. @ VcE = 3 V, Ic = 10 mA, f = 2 GHz
- · Low noise and high gain
- · Low voltage operation
- · 4-pin super minimold (18) package

★ ORDERING INFORMATION

Part Number	Quantity	Supplying Form
NE68518-A 2SC5015-A	50 pcs (Non reel)	8 mm wide embossed taping Pin 3 (Base), Pin 4 (Emitter) face the perforation side of the tape
NE68518-T1-A 2SC5015-T1-A	3 kpcs/reel	Fill 3 (base), Fill 4 (Emitter) face the perioration side of the tape

Remark To order evaluation samples, contact your nearby sales office.

The unit sample quantity is 50 pcs.

ABSOLUTE MAXIMUM RATINGS (TA = +25°C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	Vсво	9	V
Collector to Emitter Voltage	VCEO	6	V
Emitter to Base Voltage	VEBO	2	٧
Collector Current	lc	30	mA
Total Power Dissipation	Ptot	150	mW
Junction Temperature	Tj	150	°C
Storage Temperature	T _{stg}	-65 to +150	°C

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

The information in this document is subject to change without notice. Before using this document, please confirm that

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ELECTRICAL CHARACTERISTICS (TA = +25°C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
DC Characteristics						
Collector Cut-off Current	Ісво	Vcb = 5 V, IE = 0 mA	-	-	0.1	μΑ
Emitter Cut-off Current	ІЕВО	VEB = 1 V, Ic = 0 mA	-	-	0.1	μΑ
DC Current Gain	hfE Note 1	Vce = 3 V, Ic = 10 mA	75	-	150	-
RF Characteristics						
Gain Bandwidth Product	f⊤	Vce = 3 V, Ic = 10 mA, f = 2 GHz	-	12	-	GHz
Insertion Power Gain	S _{21e} ²	Vce = 3 V, Ic = 10 mA, f = 2 GHz	9	11	_	dB
Noise Figure	NF	Vce = 3 V, Ic = 3 mA, f = 2 GHz	-	1.5	2.5	dB
Reverse Transfer Capacitance	Cre Note 2	Vcв = 3 V, IE = 0 mA, f = 1 MHz	-	0.3	0.5	pF

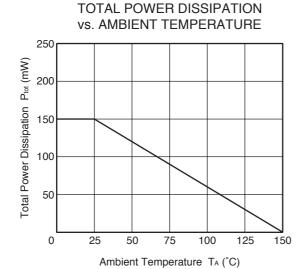
Notes 1. Pulse measurement: PW \leq 350 μ s, Duty Cycle \leq 2%

2. Collector to base capacitance when the emitter grounded

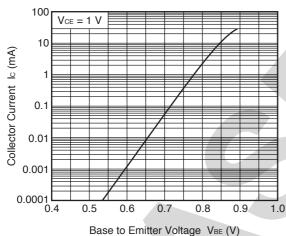
hfe CLASSIFICATION

Rank	KB		
Marking	T83		
hfe Value	75 to 150		

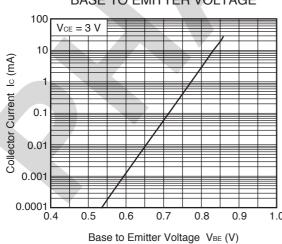
★ TYPICAL CHARACTERISTICS (T_A = +25°C, unless otherwise specified)



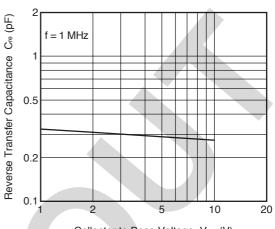
COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE



COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE

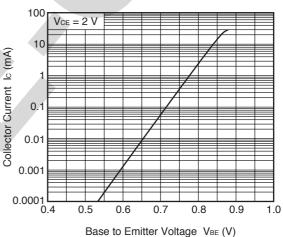


REVERSE TRANSFER CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE

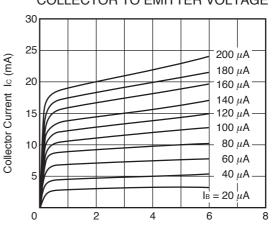


Collector to Base Voltage VcB (V)

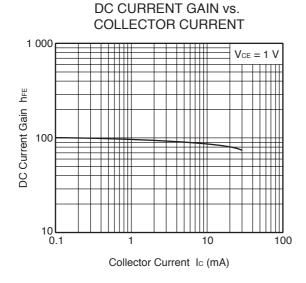
COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE



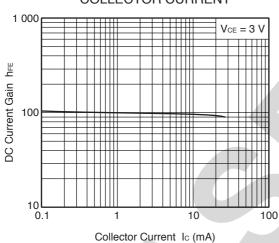
COLLECTOR CURRENT vs.
COLLECTOR TO EMITTER VOLTAGE



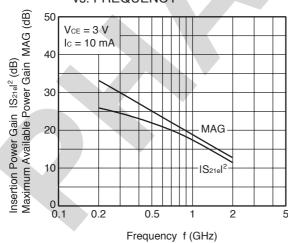
Collector to Emitter Voltage VcE (V)



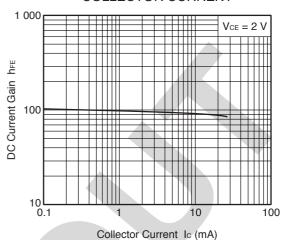




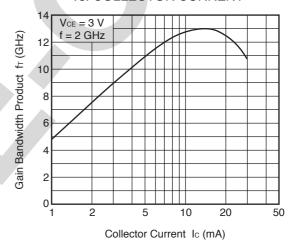
INSERTION POWER GAIN, MAG vs. FREQUENCY



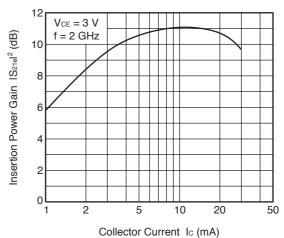
DC CURRENT GAIN vs. COLLECTOR CURRENT



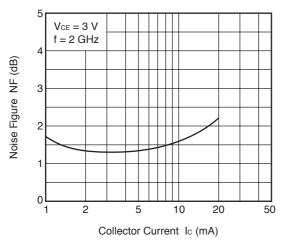
GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT



INSERTION POWER GAIN vs. COLLECTOR CURRENT



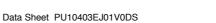




Remark The graphs indicate nominal characteristics.

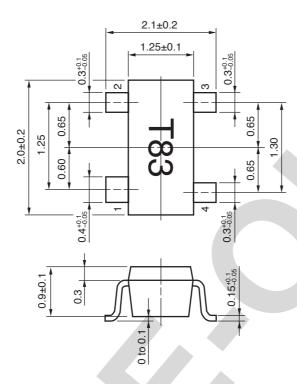
S-PARAMETERS

- S-parameters and noise parameters are provided on our Web site in a format (S2P) that enables the direct import of the parameters to microwave circuit simulators without the need for keyboard inputs.
- · Click here to download S-parameters.
- [RF and Microwave] ® [Device Parameters]
- URL http://www.necel.com/microwave/en/



PACKAGE DIMENSIONS

4-PIN SUPER MINIMOLD (18) (UNIT: mm)



PIN CONNECTIONS

- 1. Collector
- 2. Emitter
- 3. Base
- 4. Emitter

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